

# MP1924A 100V, 4A, High Frequency Half-Bridge Gate Driver

#### The Future of Analog IC Technology

# DESCRIPTION

The MP1924A is a high-frequency, half-bridge, N-channel power MOSFET driver. Its low-side and high-side driver channels are controlled independently and matched with less than 5ns of time delay. Under-voltage lockout (UVLO) on both the high-side and low-side supplies forces the outputs low in the event that the supply is insufficient. The integrated bootstrap diode reduces the external component count.

The MP1924A is available in **QFN-10** (4mmx4mm), SOIC-8, and SOIC-8E packages.

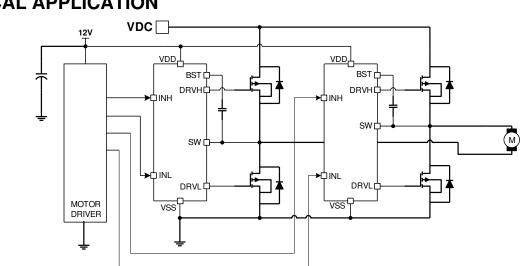
### **FEATURES**

- Drives an N-Channel MOSFET Half-Bridge
- 115V Bootstrap Voltage Range
- **On-Chip Bootstrap Diode**
- Typical Propagation Delay of 20ns •
- Gate Driver Matching of Less than 5ns •
- Drives a 2.2nF Load with 15ns of Rise Time and 12ns of Fall Time at 12V VDD
- **TTL-Compatible Input** •
- Quiescent Current of Less than 150µA
- UVLO for Both High-Side and Low-Side Gate Drivers
- Available in QFN-10 (4mmx4mm), SOIC-8, • and SOIC-8E Packages

# APPLICATIONS

- Motor Drivers •
- **Telecom Half-Bridge Power Supplies** •
- Avionics DC/DC Converters
- **Two-Switch Forward Converters**
- Active Clamp Forward Converters

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# **TYPICAL APPLICATION**

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Part Number	Package	Top Marking
MP1924AHR*	QFN-10 (4mmx4mm)	See Below
MP1924AHS**	SOIC-8	See Below
MP1924AHN***	SOIC-8E	See Below

#### **ORDERING INFORMATION**

\* For Tape & Reel, add suffix -Z (e.g. MP1924AHR-Z). For RoHS compliant packaging, add suffix -LF (e.g. MP1924AHR-LF-Z).

\*\* For Tape & Reel, add suffix -Z (e.g. MP1924AHS–Z). For RoHS compliant packaging, add suffix -LF (e.g. MP1924AHS-LF-Z).

1 HOHS compliant packaging, add Sunix -LF (e.g. MF 1924AHS-LF-2

\*\*\* For Tape & Reel, add suffix –Z (e.g. MP1924AHN-Z). For RoHS compliant packaging, add suffix -LF (e.g. MP1924AHN–LF-Z).

## **TOP MARKING (MP1924AHR)**

# MPSYWW M1924A LLLLLL

MPS: MPS prefix Y: Year code WW: Week code M1924A: Product code of MP1924AHR LLLLLL: Lot number

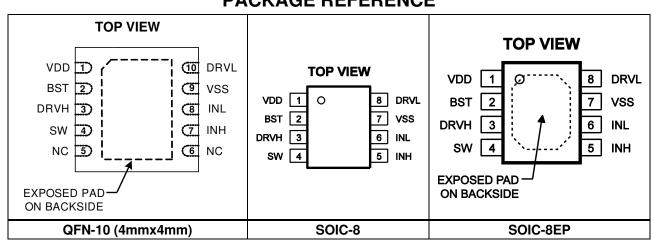
### TOP MARKING (MP1924AHS and MP1924AHN)

MP1924A LLLLLLLL MPSYWW

MP1924A: Part number LLLLLLL: Lot number MPS: MPS prefix Y: Year code WW: Week code LLL: Lot number

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### **PACKAGE REFERENCE**

### **ABSOLUTE MAXIMUM RATINGS** (1)

$\begin{array}{llllllllllllllllllllllllllllllllllll$
Storage temperature

#### **Recommended Operating Conditions** <sup>(3)</sup>

Supply voltage (V <sub>DD</sub> )	8.0V to 15.0V
SW voltage (V <sub>SW</sub> )	1.0V to 100V
SW slew rate	<<50V/ns
Operating junction temp $(T_J = T_J)$	Τ <sub>Α</sub> )

#### Thermal Resistance $^{(4)}$ $\theta_{JA}$ $\theta_{JC}$

QFN-10 (4mmx4mm)	47	7 °C/W
SOIC-8.		
SOIC8E	29.8	6.4 °C/W

#### Notes:

- 1) Exceeding these ratings may damage the device.
- 2) The maximum allowable power dissipation is a function of the maximum junction temperature T<sub>J</sub> (MAX), the junction-toambient thermal resistance  $\theta_{JA}$ , and the ambient temperature T<sub>A</sub>. The maximum allowable continuous power dissipation at any ambient temperature is calculated by P<sub>D</sub> (MAX) = (T<sub>J</sub>(MAX)-T<sub>A</sub>)/ $\theta_{JA}$ . Exceeding the maximum allowable power dissipation produces an excessive die temperature, causing the regulator to go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- 3) The device is not guaranteed to function outside of its operating conditions.
- 4) Measured on JESD51-7, 4-layer PCB.



# **ELECTRICAL CHARACTERISTICS**

 $V_{DD} = V_{BST} - V_{SW} = 12V$ ,  $V_{SS} = V_{SW} = 0V$ , no load at DRVH and DRVL,  $T_J = -40^{\circ}C$  to  $+125^{\circ}C$ , typical value is tested at  $T_J = 25^{\circ}C$ , unless otherwise noted.

Parameter	Symbol	Condition	Min	Тур	Max	Units
Supply Currents						
VDD quiescent current	IDDQ	INL = INH = 0		100	150	μΑ
VDD operating current	Iddo	fsw = 500kHz		9		mA
Floating driver quiescent current	IBSTQ	INL = INH = 0		60	90	μA
Floating driver operating current	IBSTO	fsw = 500kHz		7.5		mA
Leakage current	I <sub>LK</sub>	BST = SW = 100V		0.05	1	μΑ
Inputs						
INL/INH high				2	2.4	V
INL/INH low			1	1.4		V
INL/INH internal pull-down	R <sub>IN</sub>			185		kΩ
resistance	ΠIN			100		K12
Under-Voltage Protection						
VDD rising threshold	Vddr		6	6.8	7.2	V
VDD hysteresis	Vddh			0.5		V
BST-SW rising threshold	VBSTR		5.8	6.5	6.9	V
BST-SW hysteresis	V <sub>BSTH</sub>			0.5		V
Bootstrap Diode						
Bootstrap diode VF at 100µA	V <sub>F1</sub>			0.5		V
Bootstrap diode VF at 100mA	V <sub>F2</sub>			0.95		V
Bootstrap diode dynamic R	RD	at 100mA		2.5		Ω
Low-Side Gate Driver						
Low level output voltage	Voll	lo = 100mA		0.1		V
High level output voltage to rail	VOHL	I <sub>O</sub> = -100mA		0.36		V
Source current <sup>(5)</sup>	Іон∟	$V_{DRVL} = 0V, V_{DD} = 12V$		3		Α
Source current (%)		$V_{DRVL} = 0V, V_{DD} = 16V$		4.7		Α
Sink current <sup>(5)</sup>		$V_{DRVL} = V_{DD} = 12V$		4.5		Α
Sink current (%)	Ioll	$V_{DRVL} = V_{DD} = 16V$		6		Α
Floating Gate Driver						
Low level output voltage	Volh	lo = 100mA		0.1		V
High level output voltage to rail	Vонн	lo = -100mA		0.32		V
Source current <sup>(5)</sup>	I <sub>ОНН</sub>	$V_{DRVH} = 0V, V_{DD} = 12V$		2.6		Α
		$V_{DRVH} = 0V, V_{DD} = 16V$		4		Α
Sink current <sup>(5)</sup>	L.	$V_{DRVH} = V_{DD} = 12V$		4.5		Α
	Iolh	$V_{DRVH} = V_{DD} = 16V$		5.9		Α



# ELECTRICAL CHARACTERISTICS (continued)

 $V_{DD} = V_{BST} - V_{SW} = 12V$ ,  $V_{SS} = V_{SW} = 0V$ , no load at DRVH and DRVL,  $T_J = -40^{\circ}C$  to  $+125^{\circ}C$ , typical value is tested at  $T_J = 25^{\circ}C$ , unless otherwise noted.

Parameter	Symbol	Condition	Min	Тур	Max	Units
Switching Specification—Low-Side Gate Driver						
Turn-off propagation delay INL falling to DRVL falling	TDLFF			20		ns
Turn-on propagation delay INL rising to DRVL rising	T <sub>DLRR</sub>			20		
DRVL rise time		C∟ = 2.2nF		15		ns
DRVL fall time		C∟ = 2.2nF		15		ns
Switching Specification—Floatin	ng Gate D	river				-
Turn-off propagation delay INH falling to DRVH falling	TDHFF			20		ns
Turn-on propagation delay INH rising to DRVH rising	T <sub>DHRR</sub>			20		ns
DRVH rise time		C∟ = 2.2nF		15		ns
DRVH fall time		C∟ = 2.2nF		15		ns
Switching Specification—Match	ing					-
Floating driver turn-off to low side driver turn-on <sup>(5)</sup>	T <sub>MON</sub>			1	5	ns
Low-side driver turn-off to floating driver turn-on <sup>(5)</sup>	TMOFF			1	5	ns
Minimum input pulse width that changes the output <sup>(5)</sup>	$T_{PW}$				50	ns
Bootstrap diode turn-on or turn-off time <sup>(5)</sup>	T <sub>BS</sub>			10		ns
Thermal shutdown				150		°C
Thermal shutdown hysteresis				25		°C

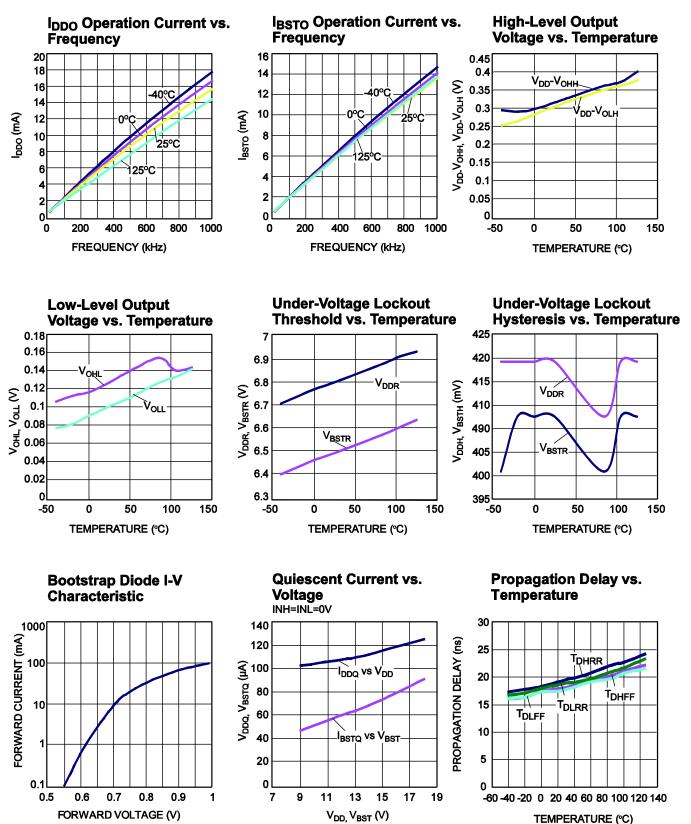
Note:

5) Guaranteed by design.



# **TYPICAL PERFORMANCE CHARACTERISTICS**

 $V_{DD}$  = 12V,  $V_{SS}$  =  $V_{SW}$  = 0V,  $T_A$  = 25°C, unless otherwise noted.



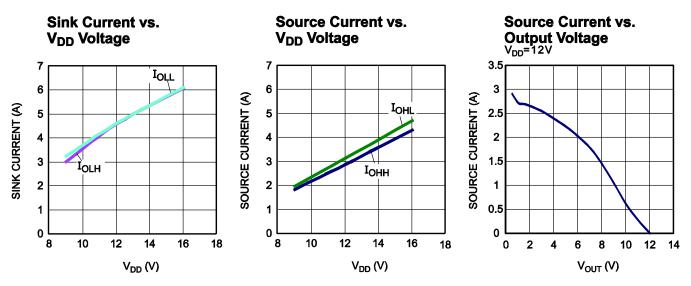
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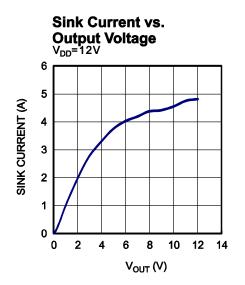
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# TYPICAL PERFORMANCE CHARACTERISTICS (continued)

 $V_{DD}$  = 12V,  $V_{SS}$  =  $V_{SW}$  = 0V,  $T_A$  = 25°C, unless otherwise noted.

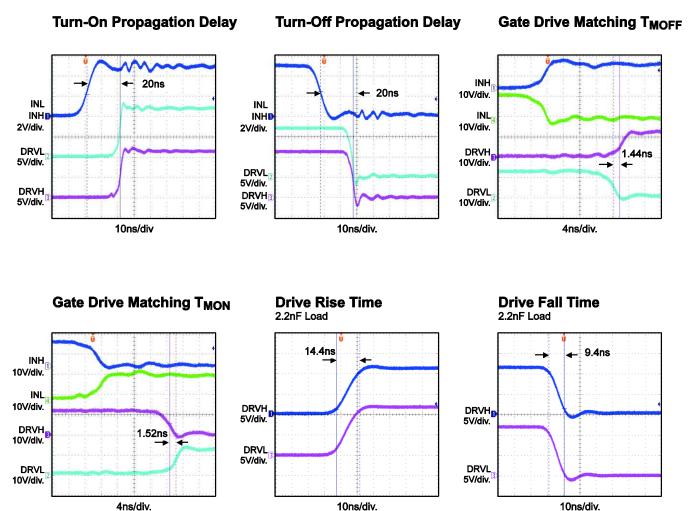






# **TYPICAL PERFORMANCE CHARACTERISTICS** (continued)

 $V_{\text{DD}}$  = 12V,  $V_{\text{SS}}$  =  $V_{\text{SW}}$  = 0V,  $T_{\text{A}}$  = 25°C, unless otherwise noted.





### **PIN FUNCTIONS**

F	Pin #				
QFN-10	SOIC-8 and SOIC-8E	Name	Description		
1	1	VDD	<b>Supply input.</b> VDD supplies power to the internal circuitry. Place a decoupling capacitor on ground close to VDD to ensure a stable and clean supply.		
2	2	BST	<b>Bootstrap.</b> BST is the positive power supply for the internal floating high-side MOSFET driver. Connect a bypass capacitor between BST and SW.		
3	3	DRVH	Floating driver output.		
4	4	SW	Switching node.		
5, 6		NC	No connection.		
7	5	INH	Control signal input for the floating driver.		
8	6	INL	Control signal input for the low-side driver.		
9	7	VSS, Exposed Pad	Chip ground. Connect the exposed pad to VSS for proper thermal operation.		
10	8	DRVL	Low-side driver output.		



### **TIMING DIAGRAM**

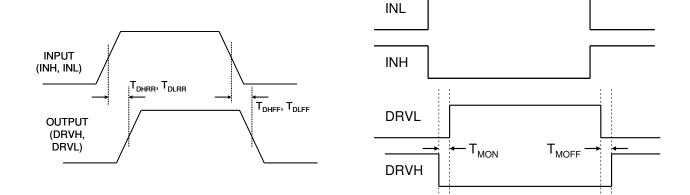


Figure 1: Timing Diagram

# FUNCTIONAL BLOCK DIAGRAM

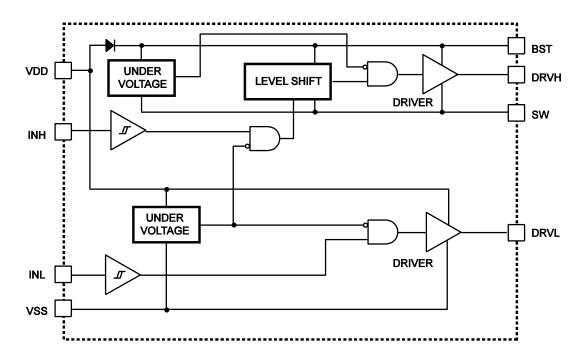
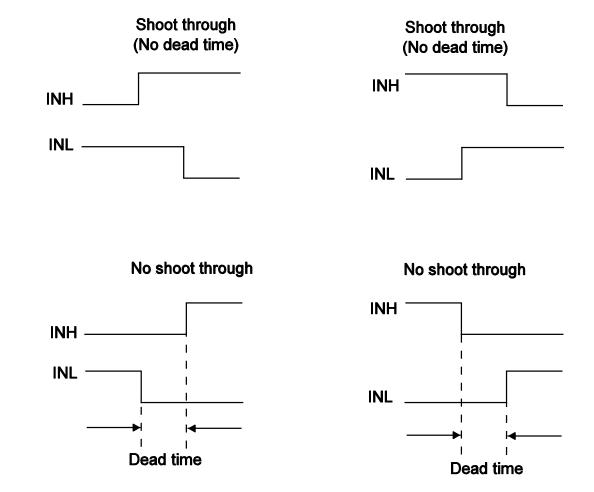


Figure 2: Functional Block Diagram



#### **APPLICATION INFORMATION**

The input signals of INH and INL can be controlled independently. If both INH and INL control the high-side and low-side MOSFETs of the same bridge, set a sufficient dead time between INH and INL low (and vice versa) to avoid a shoot-through (see Figure 3). Dead time is defined as the time interval between INH low and INL low.







### **REFERENCE DESIGN CIRCUITS**

#### Half-Bridge Converter

The MP1924A drives the MOSFETS with alternating signals with dead time in half-bridge converter topology. The input voltage can rise up

to 100V with the alternating signals INT and INL coming from the PWM controller (see Figure 4).

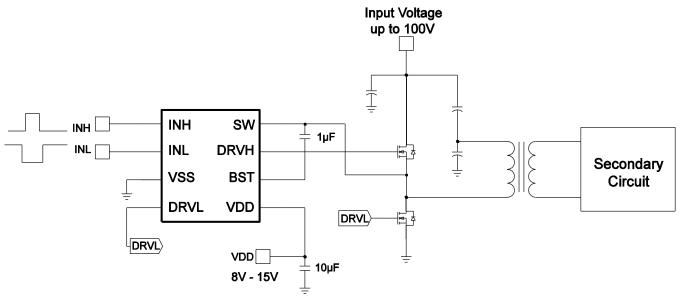
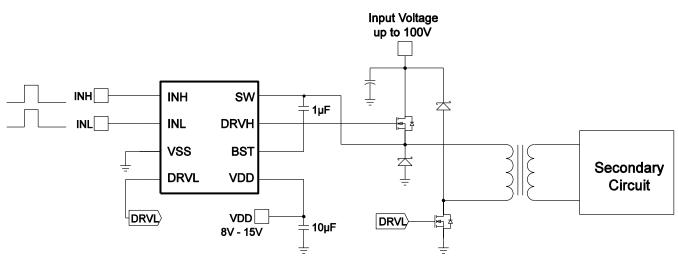


Figure 4: Half-Bridge Converter

#### **Two-Switch Forward Converter**

In two-switch forward converter topology, both MOSFETs are turned on and off simultaneously. The input signals INH and INL come from a PWM controller that senses the output voltage and output current during current-mode control.

The Schottky diodes clamp the reverse swing of the power transformer and must be rated for the input voltage. The input voltage can rise up to 100V (see Figure 5).







#### **Active Clamp Forward Converter**

In active clamp forward converter topology, the MP1924A drives the MOSFETs with alternating signals. The high-side MOSFET, in conjunction with  $C_{reset}$ , is used to reset the power transformer in a lossless manner.

This topology is optimal for running at duty cycles exceeding 50%. The device may not be able to run at 100V under this topology (see Figure 6).

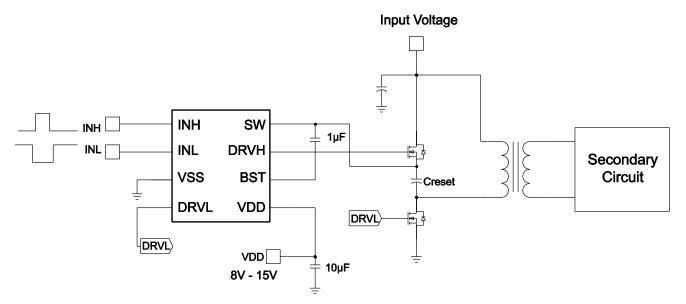
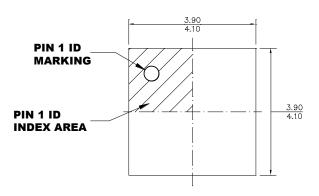


Figure 6: Active Clamp Forward Converter

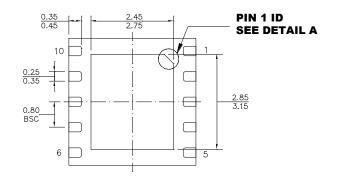


# **PACKAGE INFORMATION**

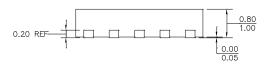


TOP VIEW

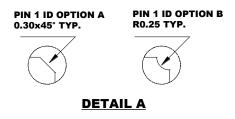


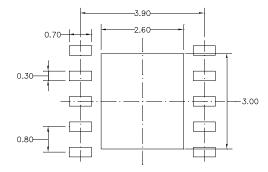


**BOTTOM VIEW** 



SIDE VIEW





#### **RECOMMENDED LAND PATTERN**

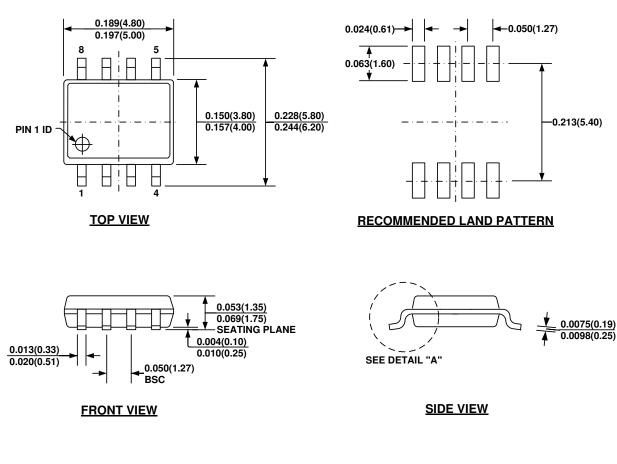
#### NOTE:

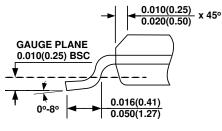
 ALL DIMENSIONS ARE IN MILLIMETERS.
EXPOSED PADDLE SIZE DOES NOT INCLUDE MOLD FLASH.
LEAD COPLANARITY SHALL BE 0.10 MILLIMETERS MAX.
JEDEC REFERENCE IS MO-220.
DRAWING IS NOT TO SCALE.



### PACKAGE INFORMATION (continued)

SOIC-8





DETAIL "A"

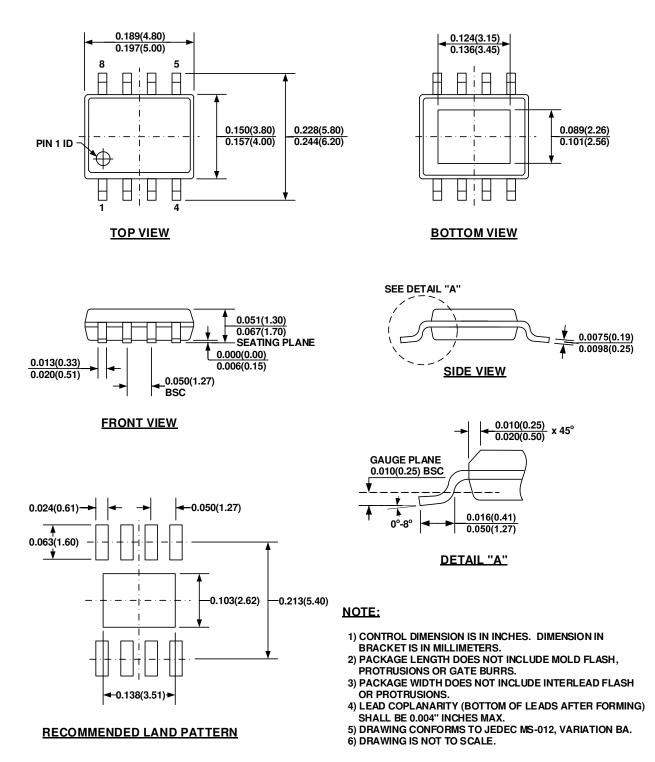
#### NOTE:

- 1) CONTROL DIMENSION IS IN INCHES. DIMENSION IN BRACKET IS IN MILLIMETERS.
- 2) PACKAGE LENGTH DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
- 3) PACKAGE WIDTH DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSIONS.
- 4) LEAD COPLANARITY (BOTTOM OF LEADS AFTER FORMING) SHALL BE 0.004" INCHES MAX.
- 5) DRAWING CONFORMS TO JEDEC MS-012, VARIATION AA.
- 6) DRAWING IS NOT TO SCALE.



## PACKAGE INFORMATION (continued)

SOIC-8EP





# **REVISION HISTORY**

Revision #	<b>Revision Date</b>	Description	Pages Updated
1.0	9/16/2015	Initial Release	-
1.1	2/09/2018	Updated the Electrical Characteristics section	5–6
		Added the SOIC-8E package information to the Description and Features sections; updated the footnote below the Applications section	1
	Added the SOIC8E package information and MP1924AHN part number information in the Ordering Information section; updated the Top Marking information; updated "– Z" to "-Z" and "–LF" to "-LF"	2	
1.2	1.2 2/22/2023	Added the SOIC-8E package information to the Absolute Maximum Ratings section	3
		Moved Note 5 to page 5; removed Note 6 (duplicate of Note 5)	5
		Added the SOIC-8E package to the Pin Functions section	9
		Added SOIC-8E package information to the Package Information section	17
		Formatting updates	All

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